



Science and
Technology
Facilities Council

Thin Film Superconducting Cavities For Sustainable Accelerators

Daniel Seal
daniel.seal@stfc.ac.uk



Lancaster
University



UNIVERSITY OF
LIVERPOOL



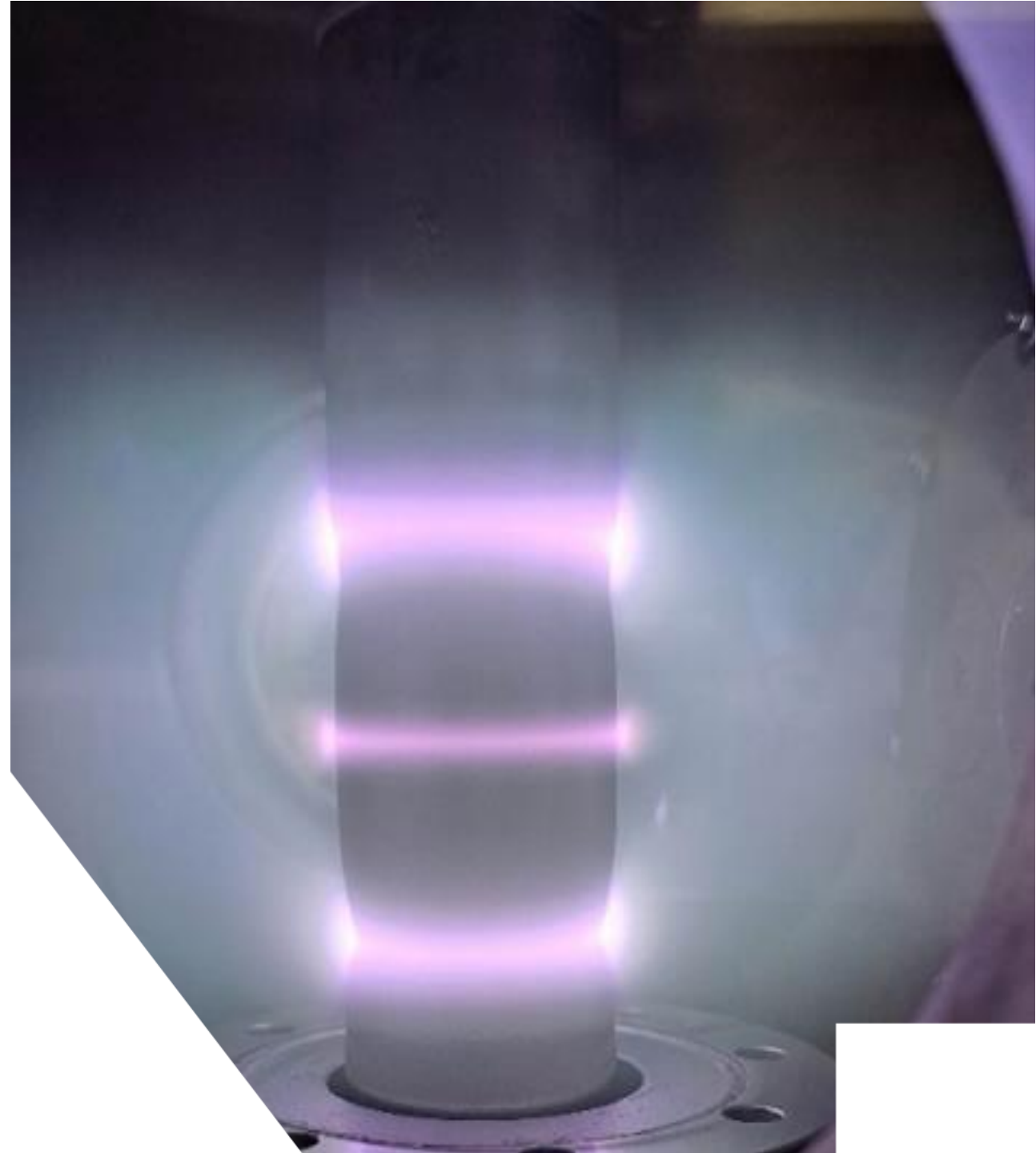
Agenda

1. Our Goal

2. Thin Film Development

3. Thin Film Testing

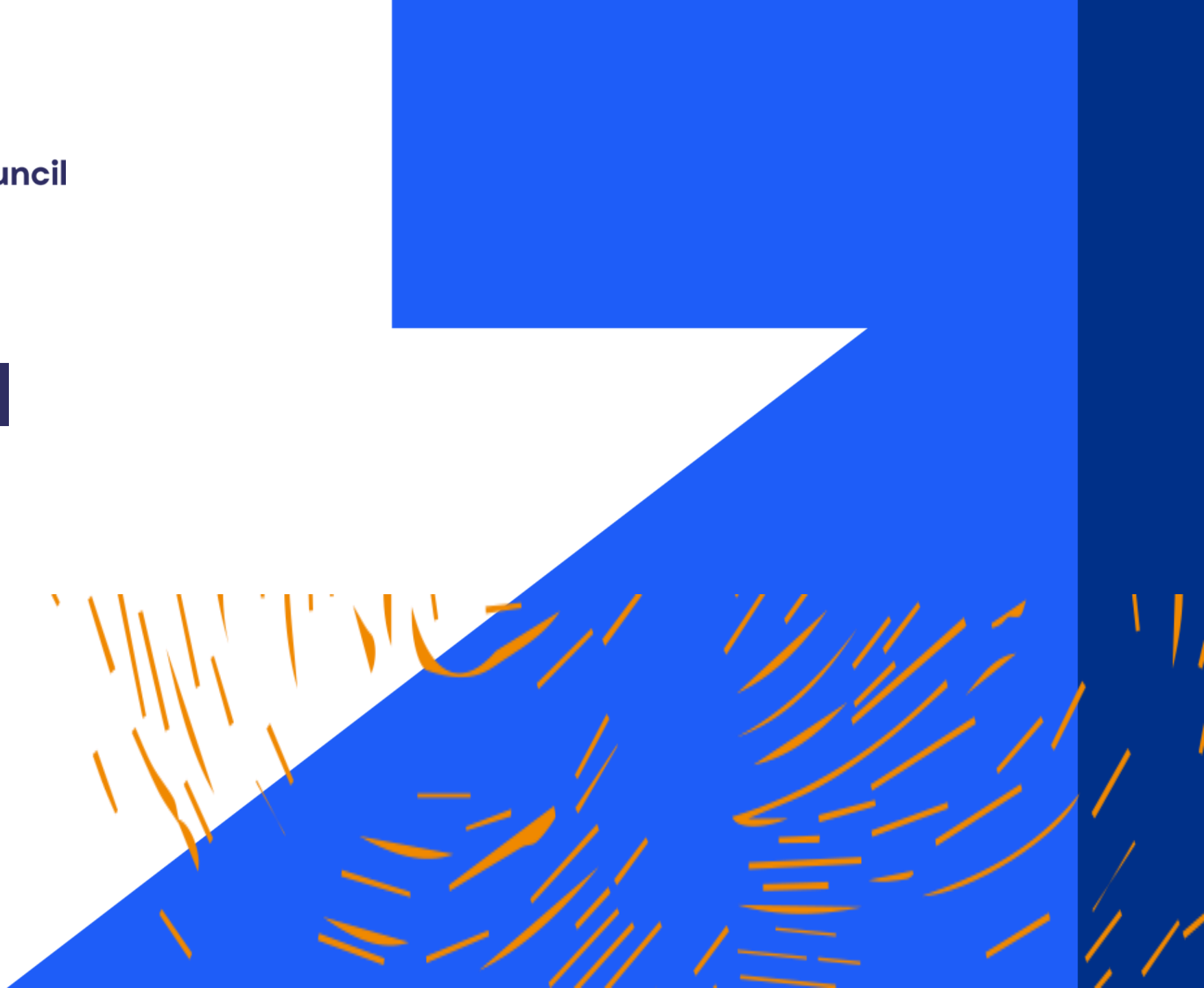
4. Future





Science and
Technology
Facilities Council

1. Our Goal



Bulk Nb Dominates SRF

- **Bulk Nb**

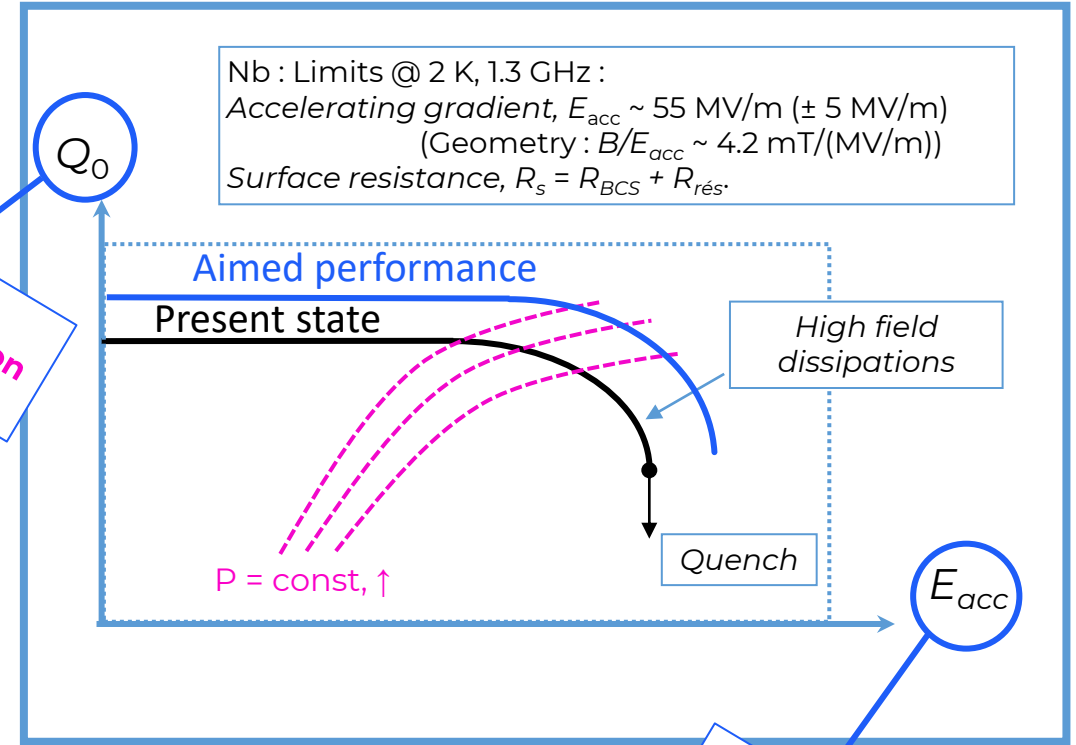
- Highest T_c , B_{c1} , B_{sh} of any element
- Large Q_0 (10^{10} - 10^{11})
- CW operation



Bulk Nb has reached limits:
 $Q_0 > 10^{10}$
 $E_{acc} > 50$ MV/m
 (1.3 GHz, 2 K)

$$Q_0 \propto \frac{1}{R_s}$$

Investment +
 Power consumption
 $Q_0 \uparrow$ Costs \downarrow

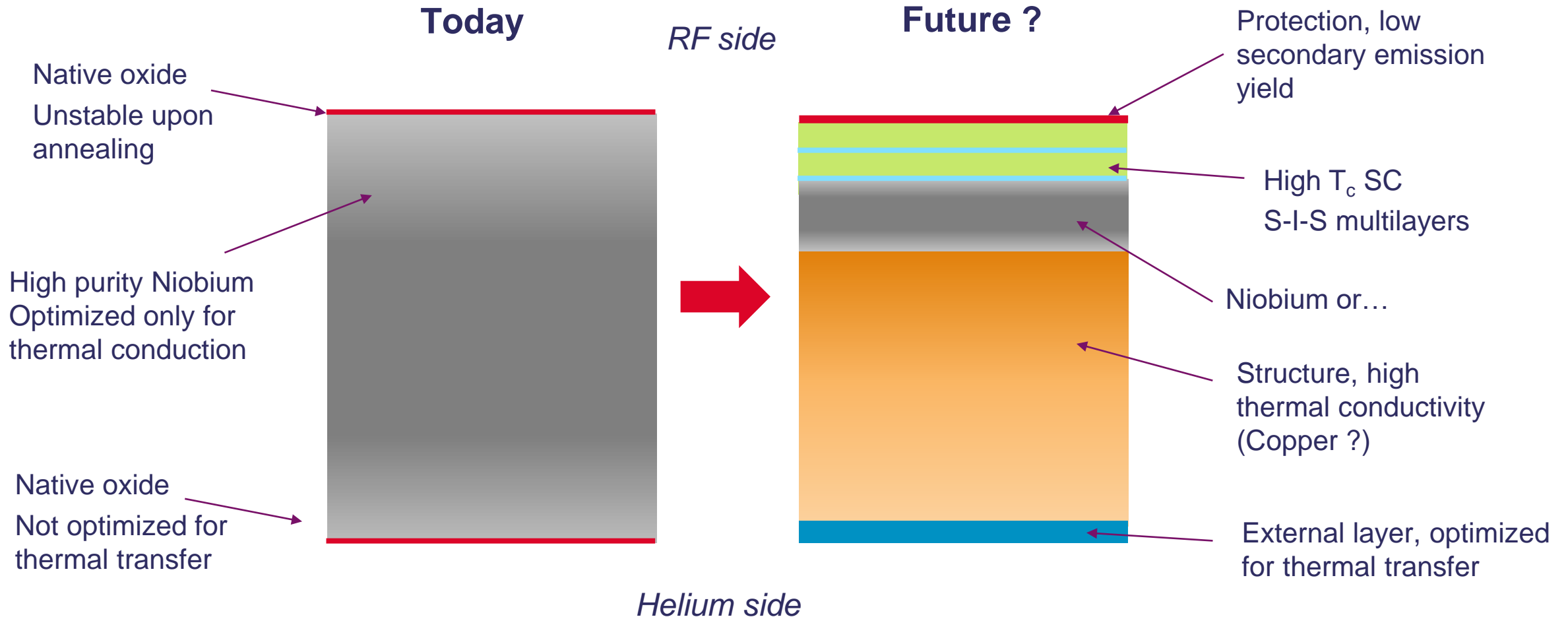


Nb : Limits @ 2 K, 1.3 GHz :
 Accelerating gradient, $E_{acc} \sim 55$ MV/m (± 5 MV/m)
 (Geometry : $B/E_{acc} \sim 4.2$ mT/(MV/m))
 Surface resistance, $R_s = R_{BCS} + R_{rés}$.

$$E_{acc} \propto B_{RF} \leq B_{sh}$$

Investment
 $E_{acc} \uparrow$ Costs \downarrow

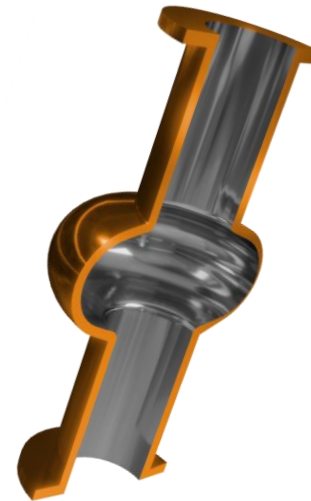
From Bulk Nb To Thin Films



Superconductors Being Considered

Material	T_c (K)	B_{sh} (mT)@ 0 K
Pb	7.1	100
Nb	9.2	219
NbTiN	17.3	439
V_3Si	17.0	490
NbN	17.3	214
Nb_3Sn	18.3	425
Nb_3Al	18.5-19.1	
MgB_2	39.0	170

High B_{sh} \rightarrow High E_{acc} \rightarrow fewer cavities



Why thin film on copper?

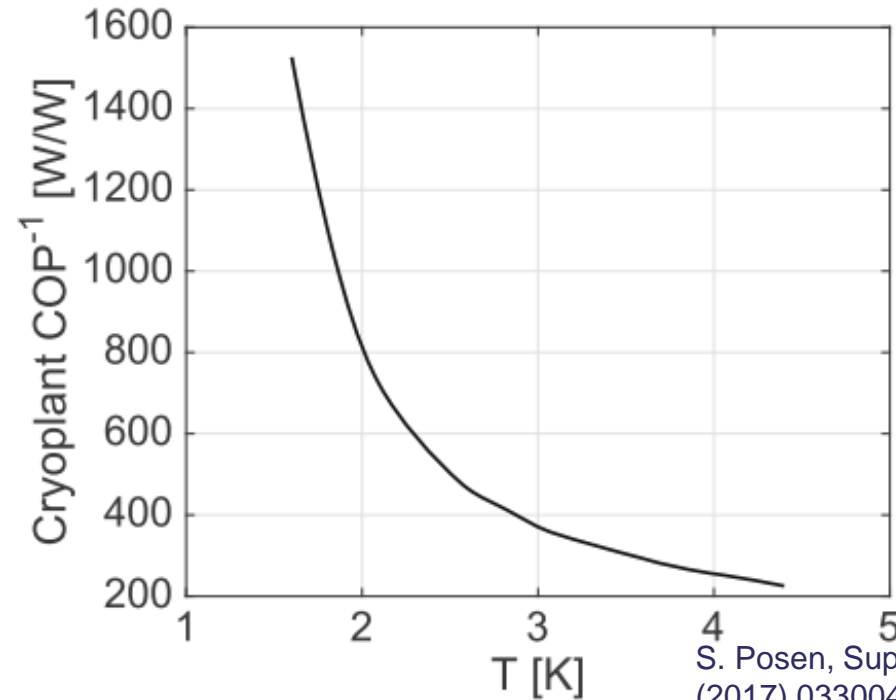
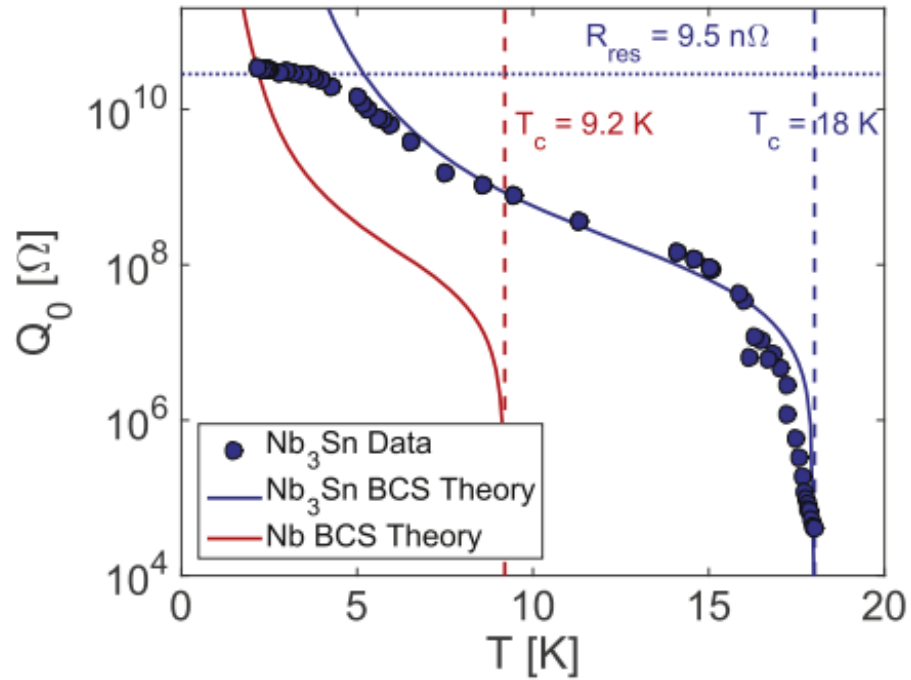
- Cheaper than Nb
- Higher thermal conductivity
- Easily machinable

High T_c \rightarrow High Q_0 \rightarrow less cooling

Courtesy of C. Antoine (CEA)

Saving Energy For Future Accelerators

Moving from 2 K to 4.5 K reduces cryogenic power by factor 3!



S. Posen, Supercond. Sci. Technol. 30 (2017) 033004

Estimated cryogenic costs of ESS (M€):

2 K (Bulk Nb)
4.5 K (Thin Film)

Infrastructure

Operation



C. Z Antoine: IPAC2023



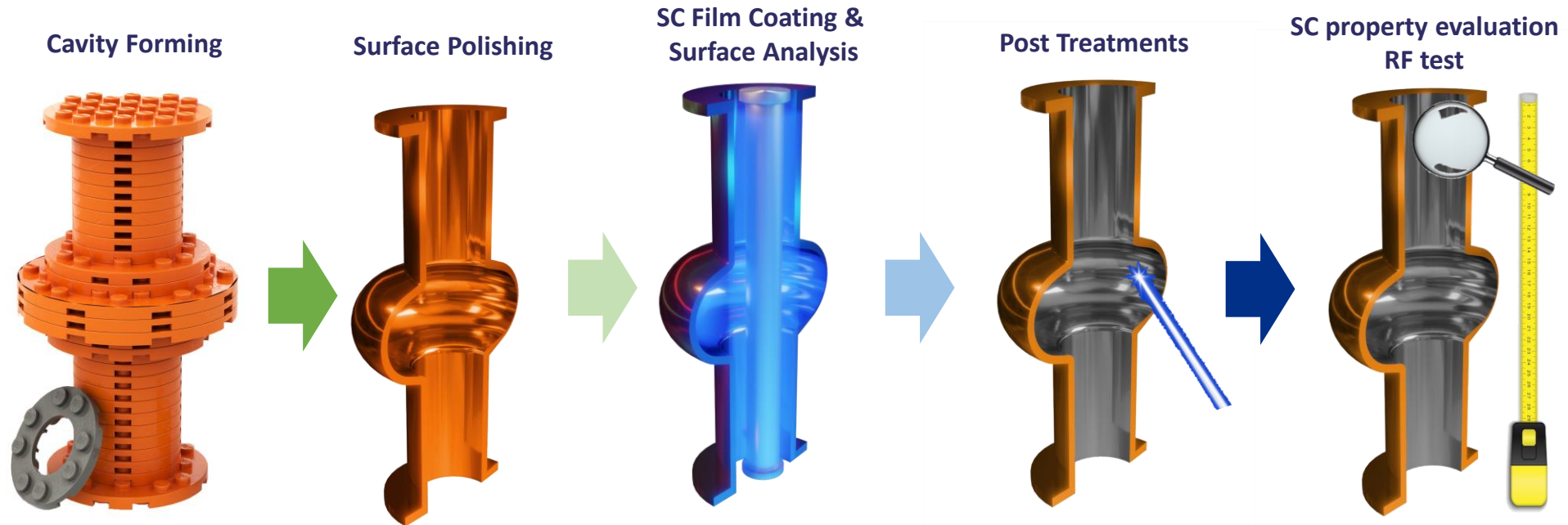
Science and
Technology
Facilities Council

2. Thin Film Development



Thin Film Pathway

Initial testing
on planar
samples



**Aim: Produce a prototype, high performance
1.3 GHz thin film SRF elliptical cavity
 $Q_0 > 10^{10}$ @ 4.5 K**

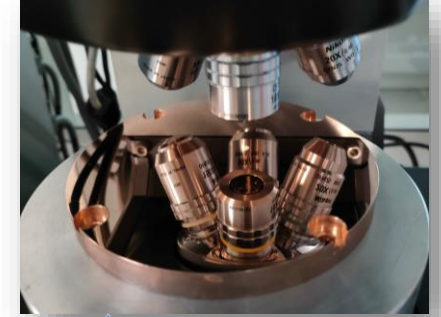
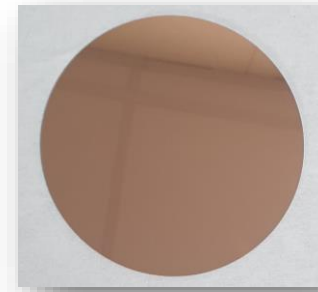


Surface Polishing

- **At STFC:**
 - Some mechanical polishing
 - Diamond turning (DT)
- **IFAST Partners:**
 - Mechanical polishing;
 - Tumbling
 - Metallographic (MP)
 - Chemical polishing
 - SUBU
 - Electropolishing (EP)
 - Plasma Electrolytic Polishing (PEP)



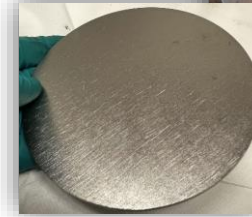
DT Cu Disk



MP Cu Disk

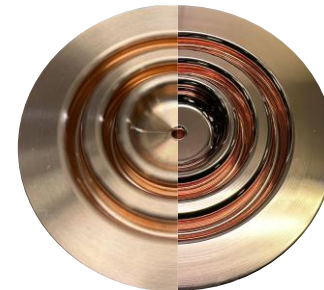


MP Nb Disk



In development at STFC

Green alternative



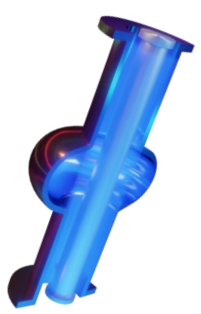
SUBU Cu Choke Cavity

PEP Quadrupole Resonator (QPR)



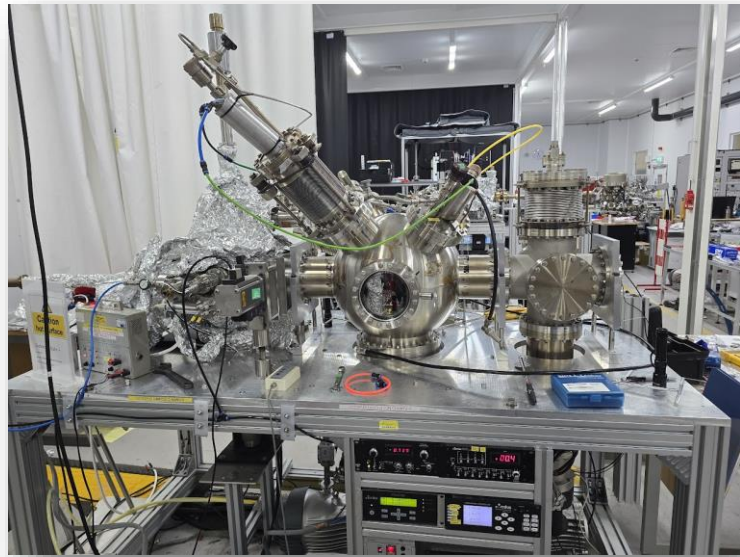
PEP 6 GHz Cavity

Courtesy of E. Chyhyrynets & C. Pira (INFN)

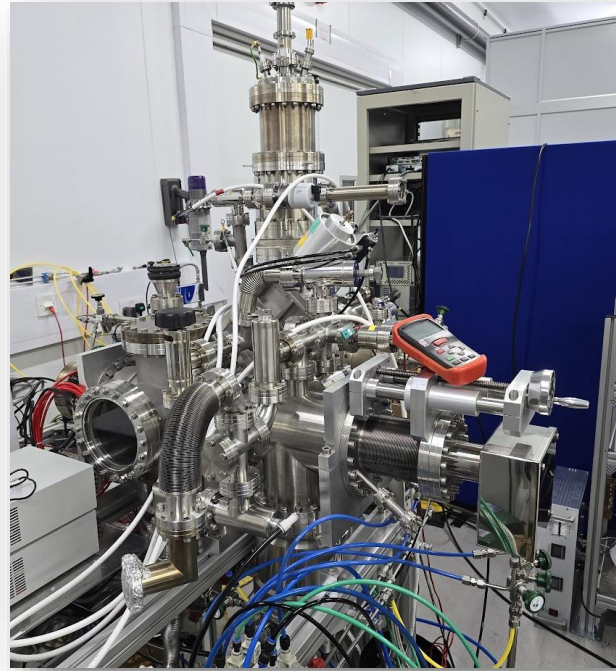


Thin Film Depositions - Planar Samples

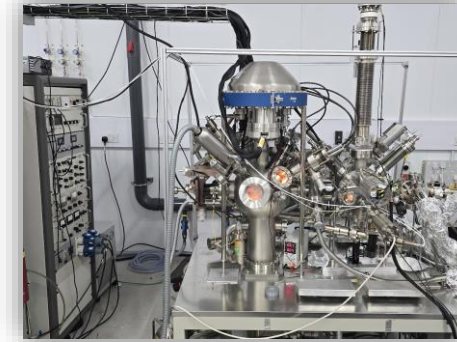
Planar samples provide a cost-effective pathway for thin film R&D



Sample disks for mass parameter optimisation



QPR samples for high RF field analysis



X-ray Photoelectron Spectroscopy



Secondary Ion Mass Spectrometry



Scanning Electron Microscopy



White Light Interferometry

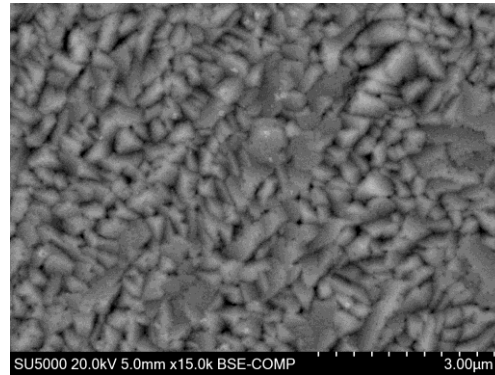
Thin Film Depositions - Planar Samples

Can Nb₃Sn sputtering match or exceed performance of Sn vapour diffusion into bulk Nb?

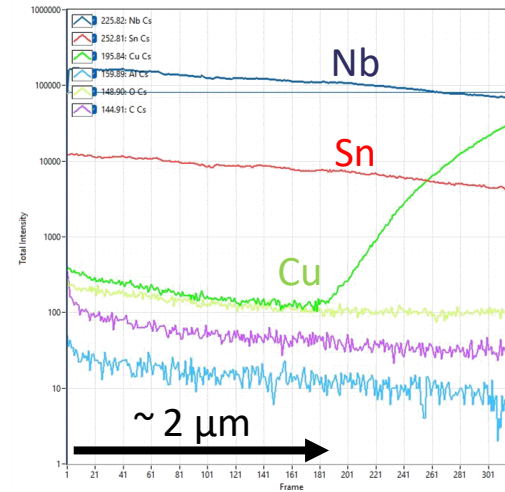
Nb₃Sn on 50-100 mm substrates

- Theoretical $T_c = 18$ K
- DC, HiPIMS
- Effect of magnetron power, deposition temperature

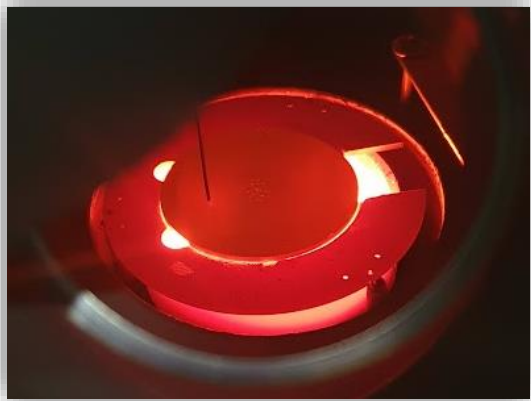
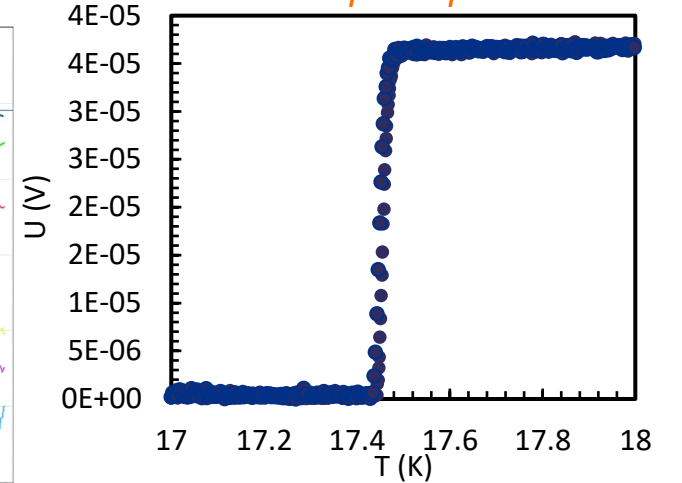
SEM – high grain density



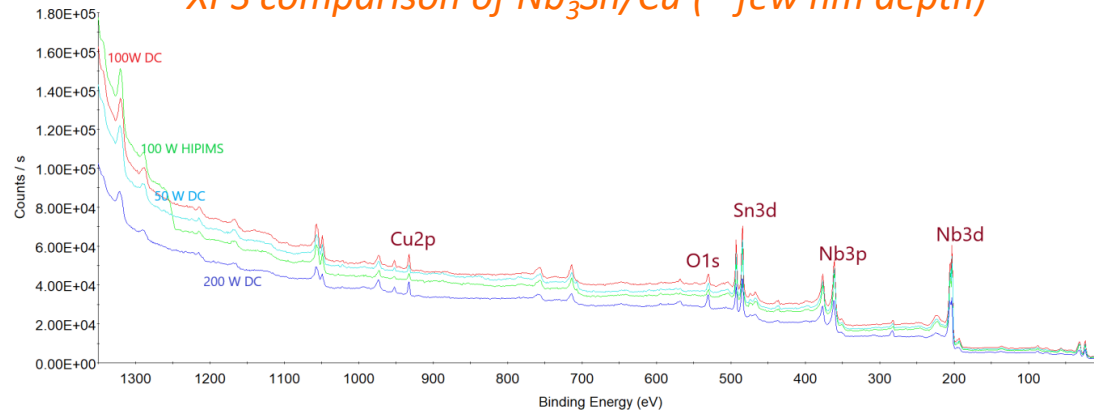
SIMS on 100 W HiPIMS



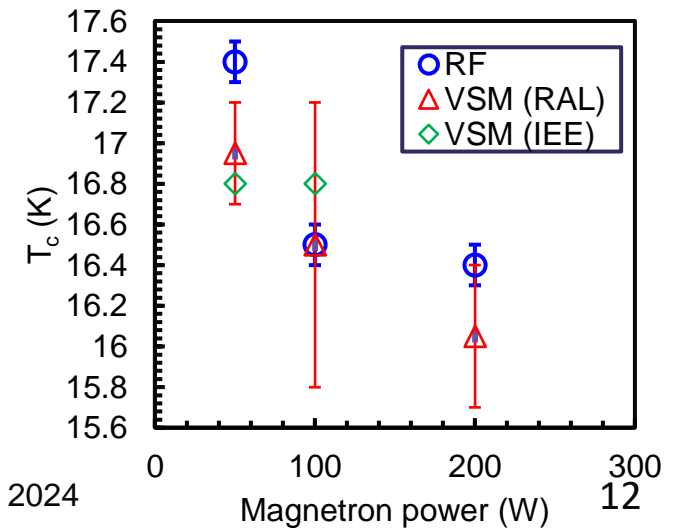
Four point probe



XPS comparison of Nb₃Sn/Cu (~ few nm depth)



Effect of DC magnetron power

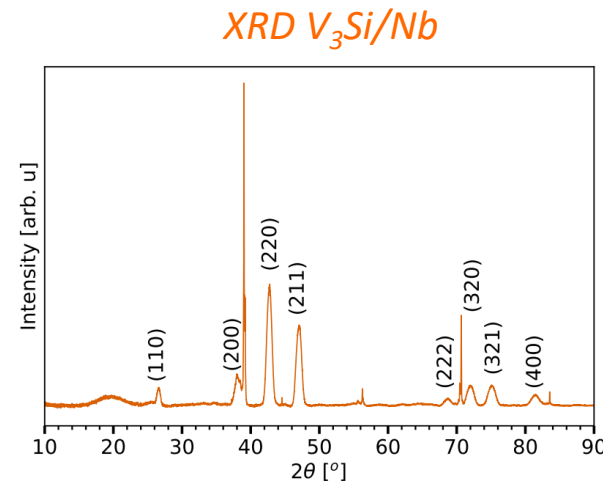
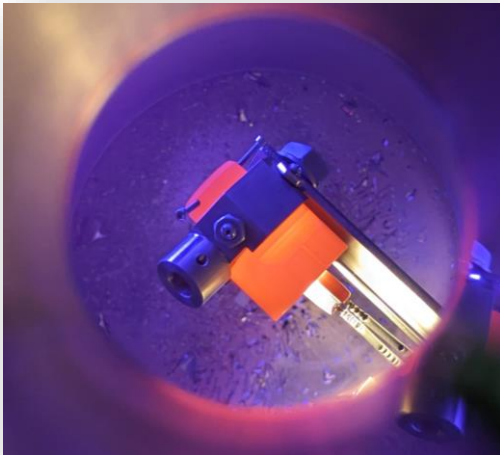


Thin Film Depositions - Planar Samples

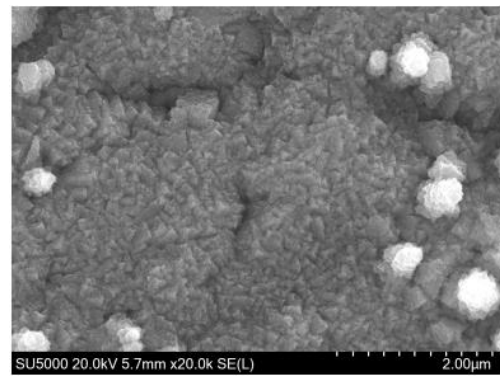
Is V_3Si a viable alternative material?

V_3Si on 10 mm substrates

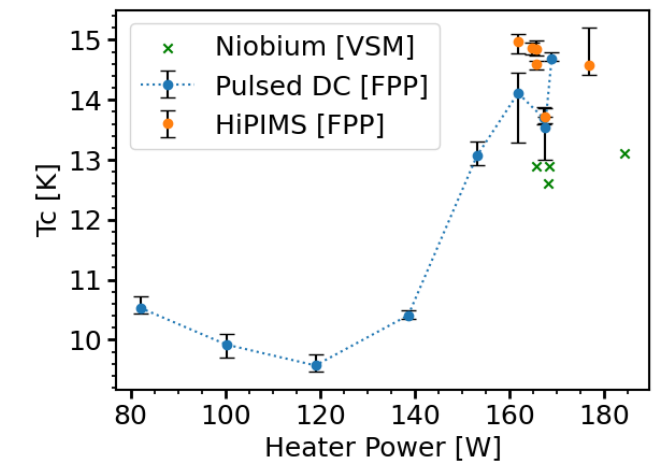
- Theoretical $T_c = 17$ K
- Initial steps to improve T_c and consistency of growth
- Post-annealing required – furnace, laser, flash lamp



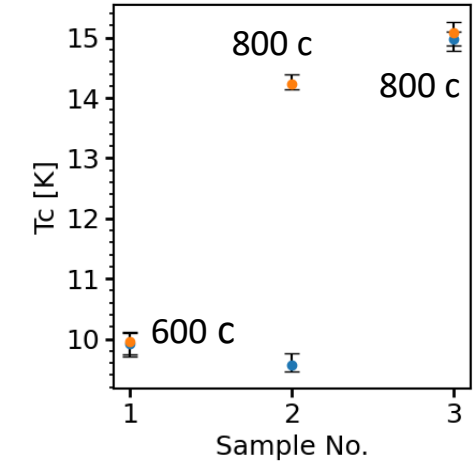
SEM – small crystallites



Effect of heater power on T_c



Effect of post-deposition annealing



C. Benjamin et al. V_3Si : An alternative thin film material for superconducting RF cavities, IPAC 24

Thin Film Depositions – 6 GHz Cavities

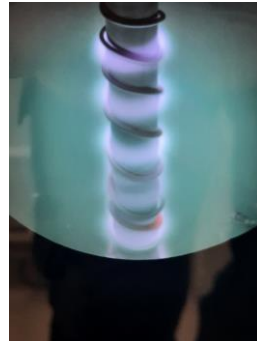
Are performances on flat geometries repeatable on curved geometries?

Closed Seamless Cavities

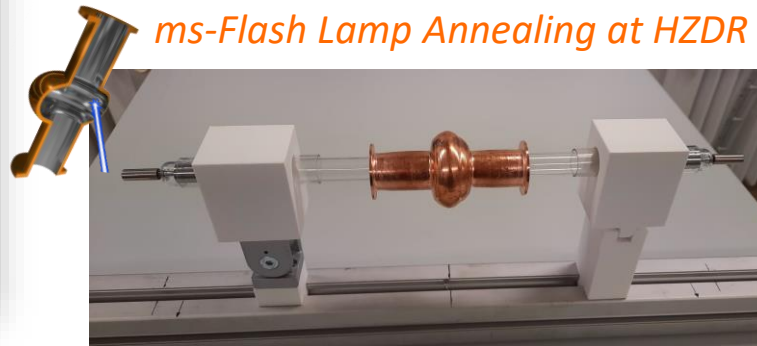
Deposition facility



Nb target
with Ti wire



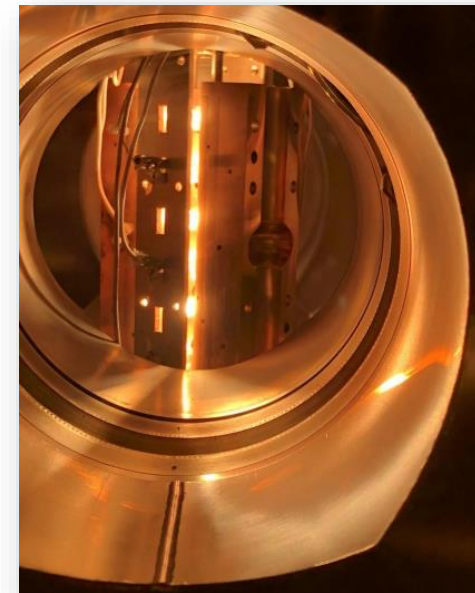
ms-Flash Lamp Annealing at HZDR



Courtesy of S. Prucnal & S. Zhou (HZDR)

Open Split Cavities

Planar magnetron



Cylindrical magnetron



Nb, NbTiN, Nb₃Sn, V₃Si

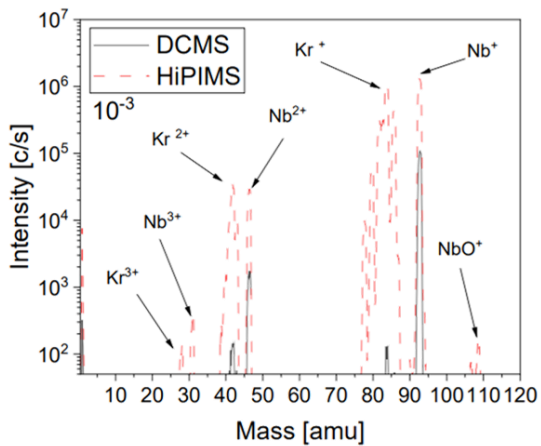
Thin Film Depositions – 1.3 GHz Cavities

Can we achieve uniform coatings on larger cavity structures?

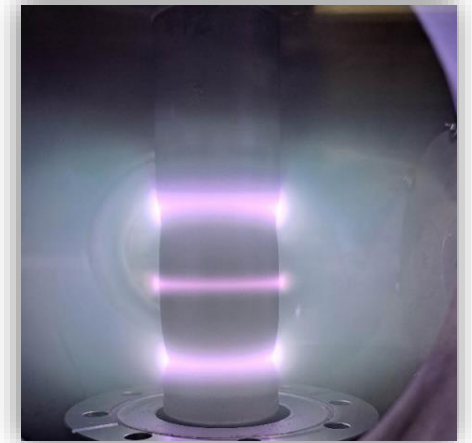
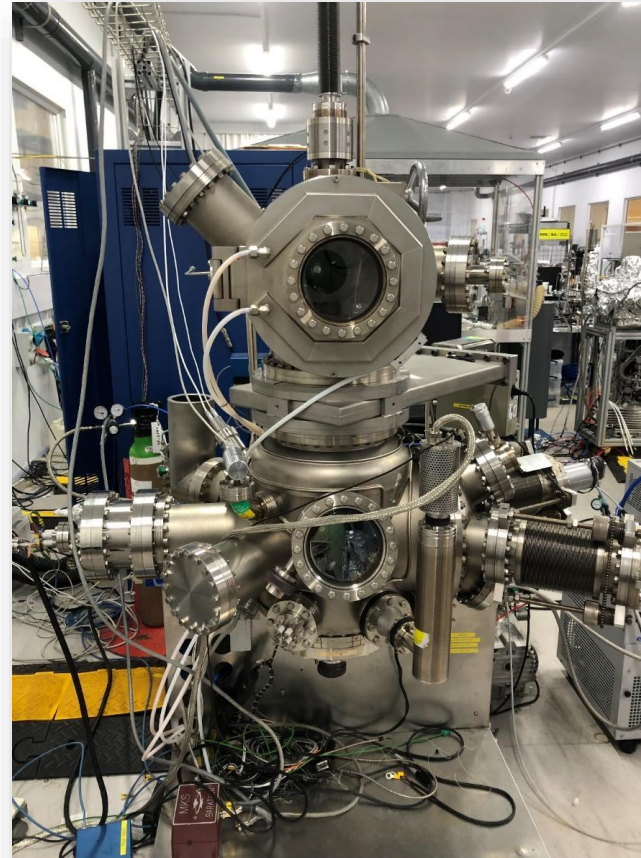
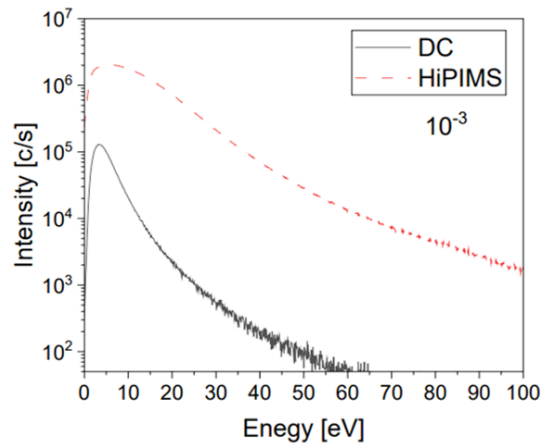
Optimising thin film deposition parameters

- Mainly Nb thin films so far
- Comparing deposition techniques (DCMS, HiPIMS)
- Plasma diagnostic studies

Mass scan at 10^{-3} mbar



Ion energy distribution function of Nb^+ at 10^{-3} mbar



S. Simon et al. Tailoring the production of Nb superconducting films for SRF cavities: mass/energy spectroscopy and film characterisation, IPAC 24



Science and
Technology
Facilities Council

3. Thin Film Testing





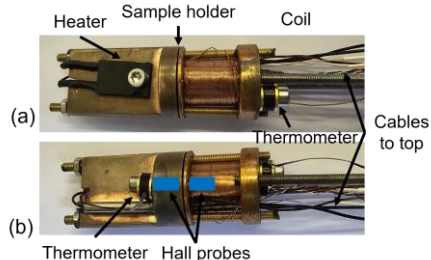
DC Superconducting Properties

Rapid sample tests with multiprobe inserts

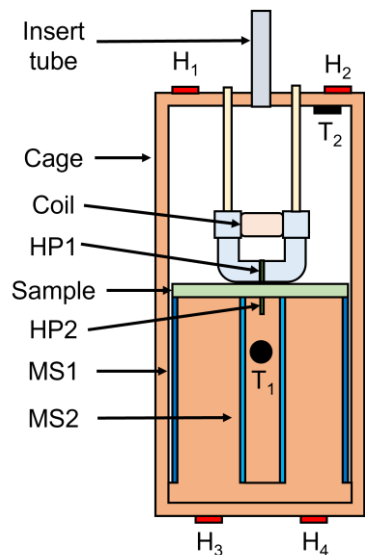
- Is the sample superconducting?
- What is its T_c ?
- What is its behaviour under high magnetic fields?

20 tests per week!

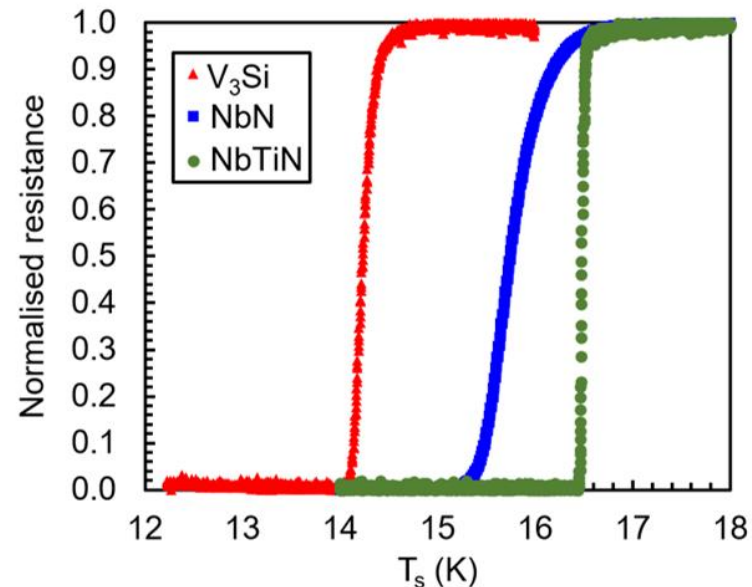
Magnetic T_c



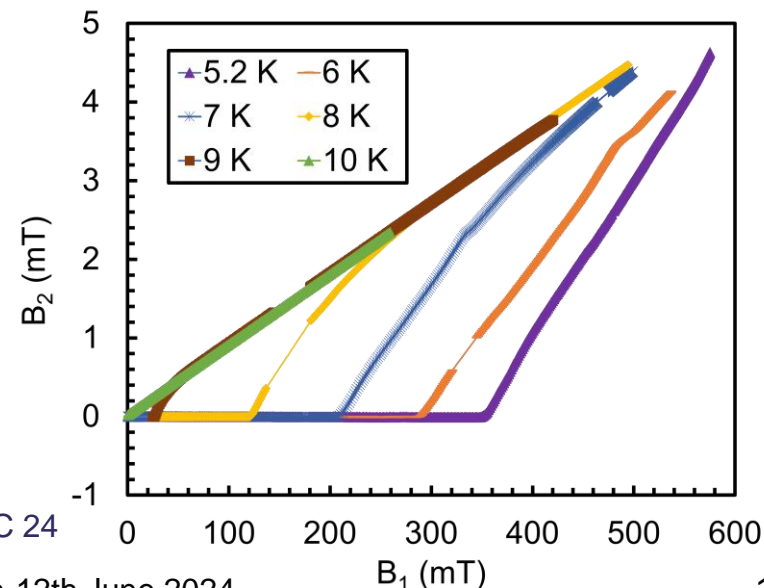
Magnetic Field Penetration



Four-point probe measurements with alternative materials



Magnetic field penetration with Nb



D. Seal et al. Upgraded multiprobe sample inserts for thin film SRF cavity developments, IPAC 24



DC Magnetic Field Penetration

3 tests per week!

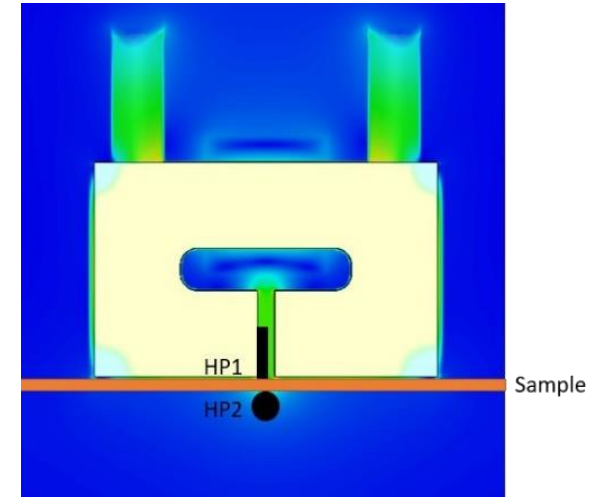
Is there a correlation between DC & RF performance?

Cavity-like DC fields applied:

- Parallel
- From one side (unlike SQUID VSM)
- $B < 600$ mT

Recently upgraded facility:

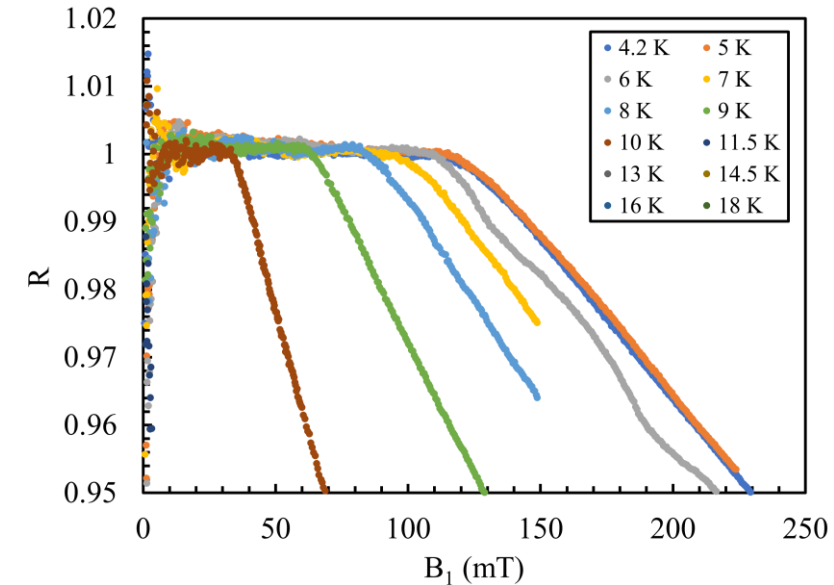
- Test 10 cm samples size and 6 GHz split cavities
- Magnetic shields
- Minimal damage to films



$V_3Si/Nb/Cu$ Sample

$$R = 1 - \frac{B_2}{B_1}$$

Meissner state when $R = 1$





RF Test With Choke Cavity

Most importantly, how does the thin film perform under RF conditions?

7.8 GHz Choke Cavity

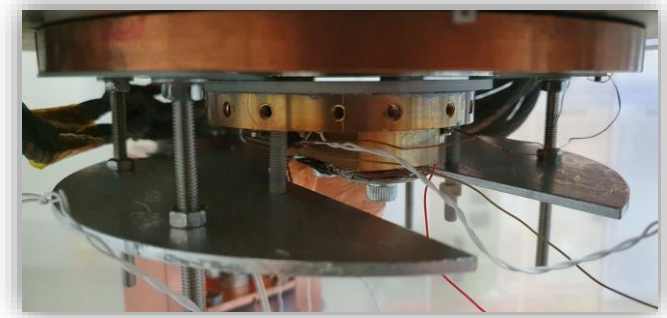
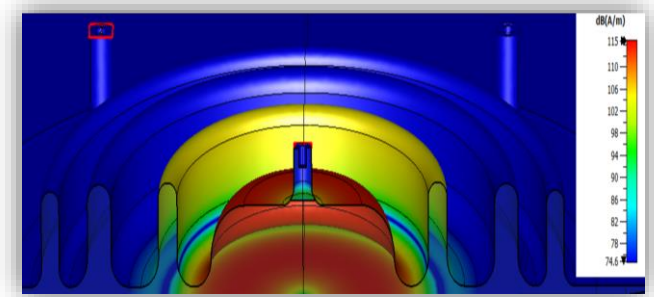
Low field measurements:

- R_s vs $B_{\text{sample, pk}}$
- R_s vs T_{sample}
- Penetration depth vs T_{sample}

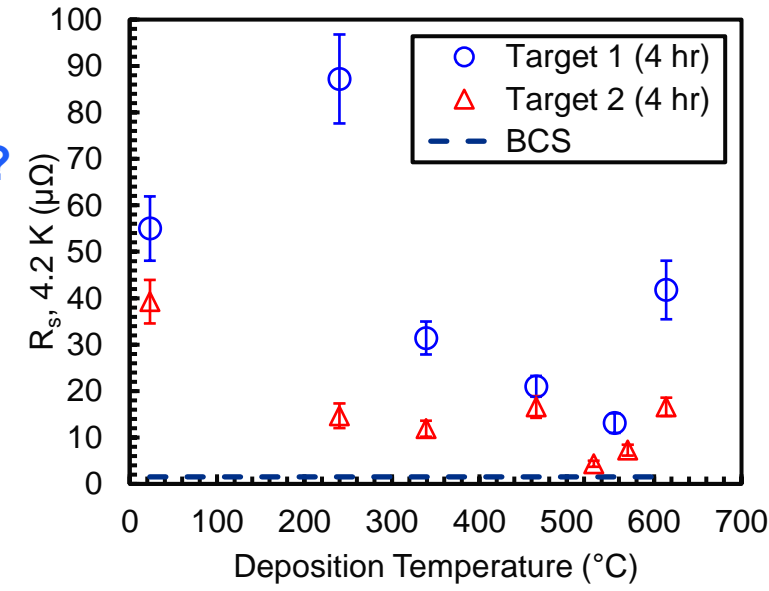
Mass parameter optimisation prior to:

- High field/low frequency tests with QPR
- Cavity tests

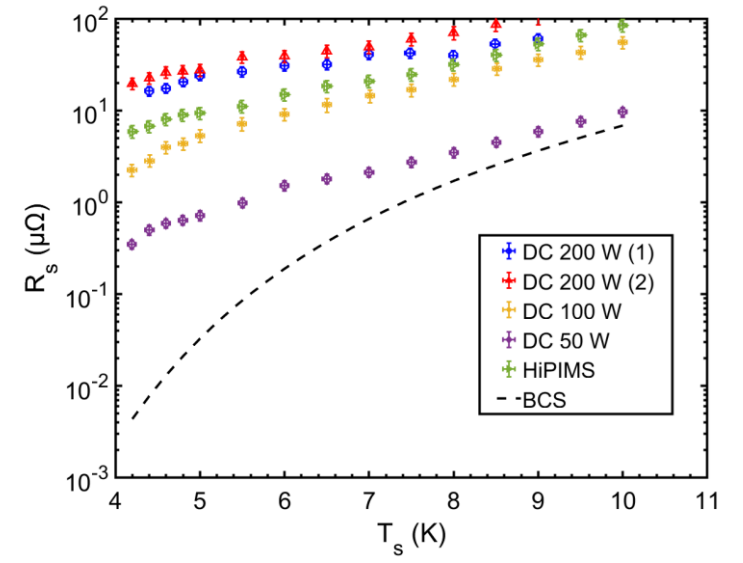
3 tests per week!



Effect of deposition temperature on Nb/Cu



Effect of magnetron power on Nb_3Sn/Cu





Low Power Cavity Testing

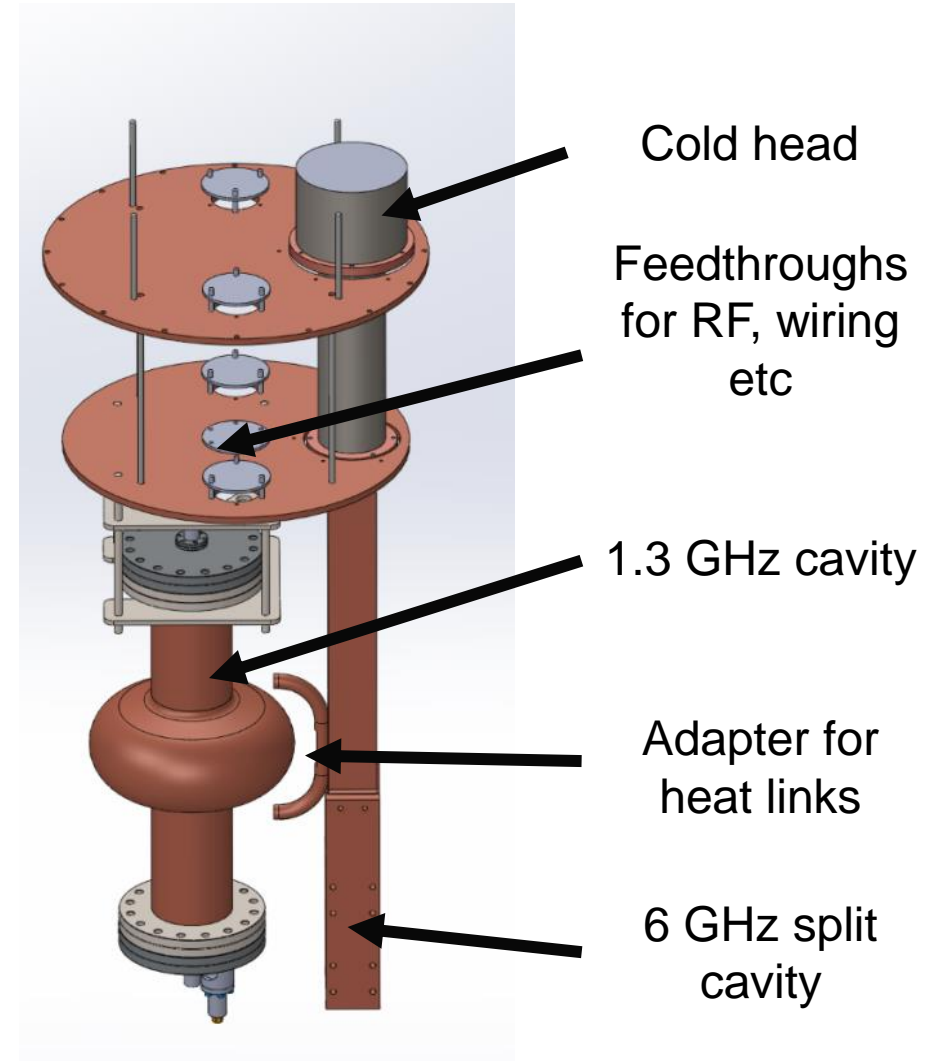
First tests
autumn 2024!

Cryocooler based facility

- $P < 2.5 \text{ W}$, $T > 4 \text{ K}$ (est.)
- Quick first cavity test
- Good cavities will have high power test in LHe

4 types of cavity

- 1.3 GHz closed
- 1.3 GHz split (in development)
- 6 GHz closed
- 6 GHz split



Courtesy of O. Poynton & J. Rigby



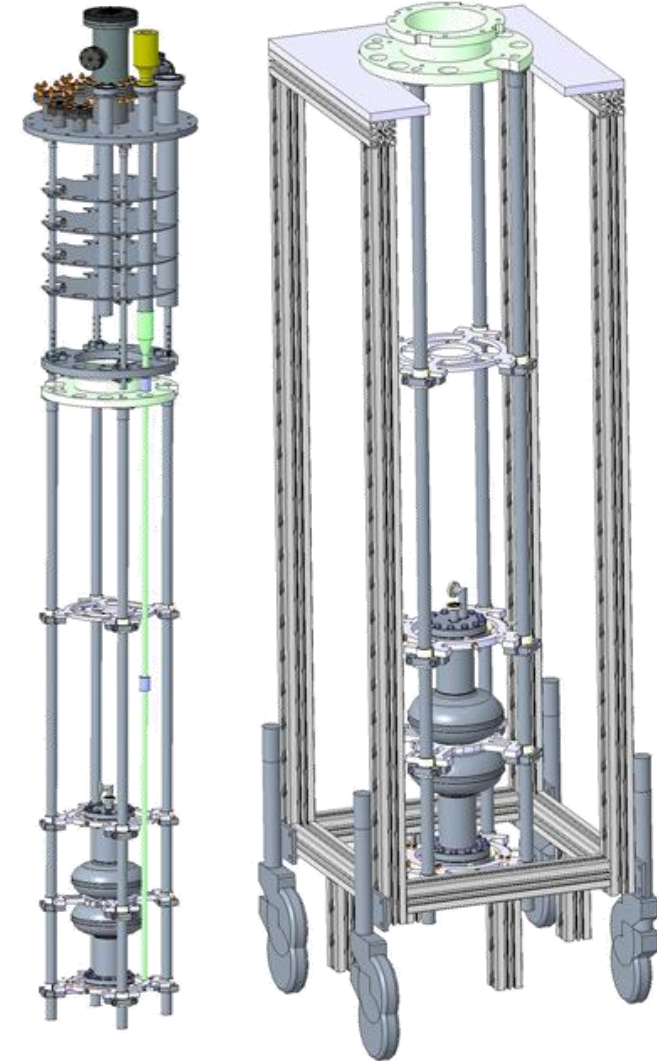
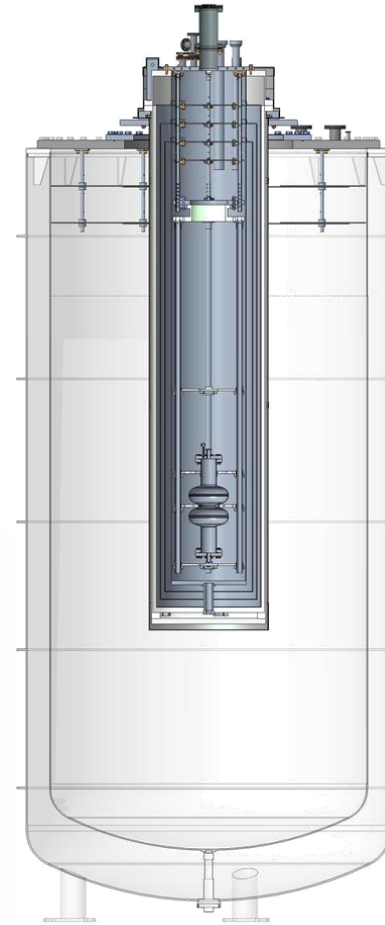
High Power Cavity Testing

First tests summer 2024!

- Full Q_0 vs E_{acc} test with LHe
- Testing with existing STFC/DL LHe infrastructure mainly used for ESS & PIP-II cavity tests
- **Upgrades now allow for:**
 - A RF single system for 650 MHz, 700 MHz and 1.3 GHz
 - $P \leq 200$ W, $T = 2$ K & 4.2 K
 - Capability for 9-cell tests



Existing SRF Test Facilities at Daresbury Laboratory

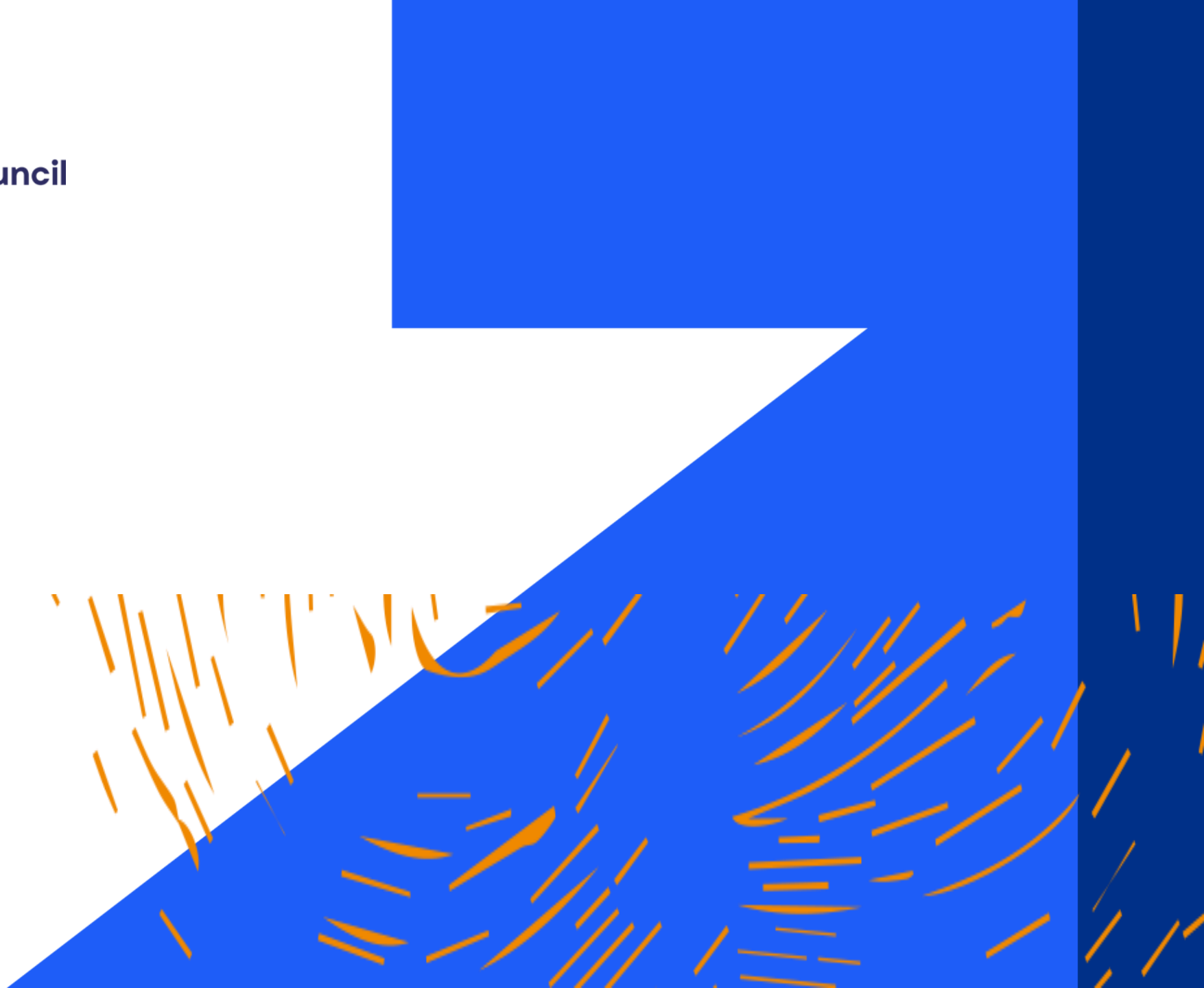


Courtesy of T. Sian & C. Hill



Science and
Technology
Facilities Council

4. Future

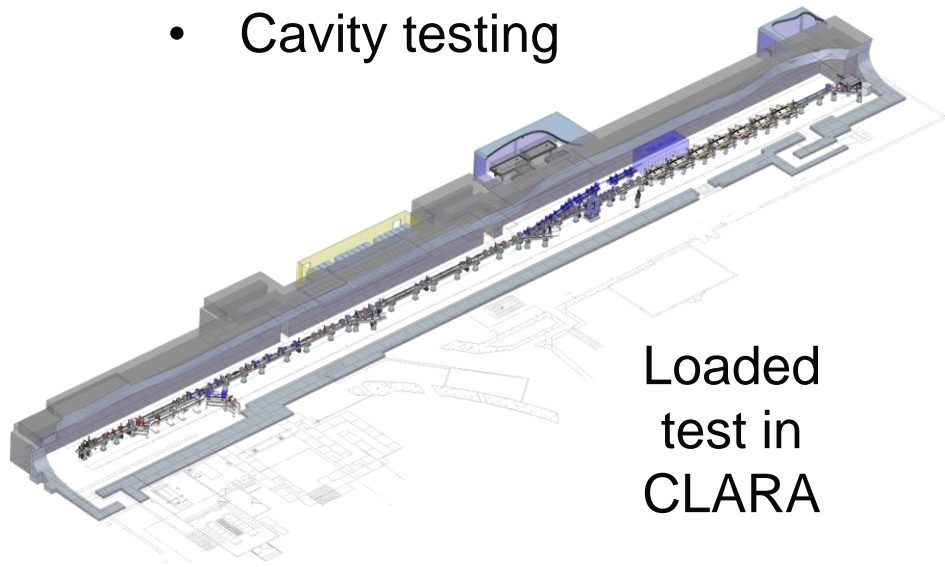


The Future of Thin Film SRF in the UK

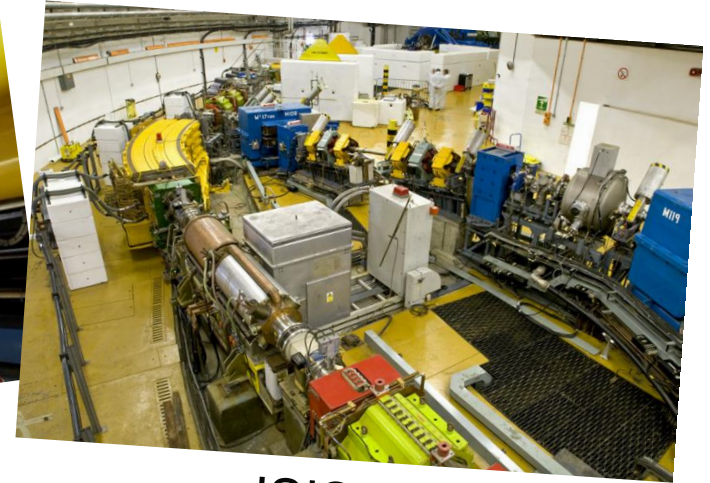
Reduce capital and running costs of accelerators!

Continuing R&D

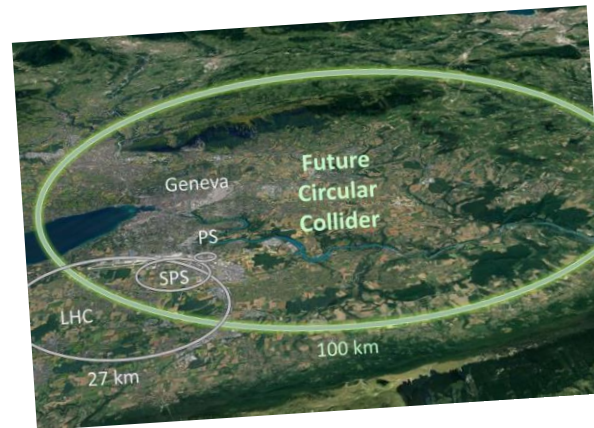
- Thin film coatings
- Post-processing
- Quick sample testing
- Split cavities
- Multi cells
- Cavity testing



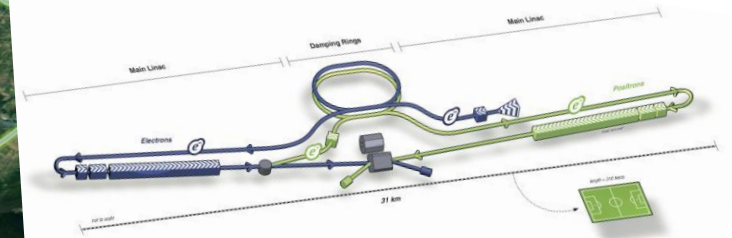
UK XFEL



ISIS II



FCC



ILC

Acknowledgements

STFC/CI: O. B. Malyshev, R. Valizadeh, C. Benjamin, O. Poynton, J. Rigby, A. Akintola, T. Sian, L. Smith, J. Conlon, C. Benjamin, S. Pattalwar, G. Miller, A. Blackett-May, A. Vick, C. Hill, M. Pendleton, M. Jones, P. Smith, A. Wheelhouse, D. Mason

Lancaster University/CI: G. Burt, N. Leicester, H. Marks, A. Mogheysheh

University of Liverpool/CI: S. Simon, J. Bradley

INFN: C. Pira, E. Chyhyrynets, D. Ford, A. Salmaso

IJCLAB: D. Longuevergne, O. Hryhorenko

CEA: C. Antoine

IEE: E. Seiler, R. Ries

HZDR: S. Prucnal, S. Zhou



Science and
Technology
Facilities Council

Thank you



Science and Technology Facilities Council



@STFC_matters



Science and Technology Facilities Council